## Slotted Optical Flag Switch OPB850A, OPB850-1Z



### Features:

- Snap into PCBoard mounting
- Transistor output
- Mechanical switch replacement
- Four 18" (457 mm) 26 AWG, UL wires for electrical connections
- · Choice of phototransistor or Rbe phototransistor output



#### **Description:**

Each **OPB850A** switch has a NPN phototransistor coupled with a 940 nm gallium arsenide infrared emitting diode in a molded plastic housing. Each **OPB850-1Z** has a Rbe phototransistor coupled with an 880 nm gallium arsenide infrared emitting diode in a molded plastic housing. An actuated lever arm flag interrupts the light beam, which switches the transistor output between states that can readily drive logic gates.

These devices are designed to replace conventional mechanical limit switches where long life and reliability are critical. The switches are designed to easily snap mount into a 0.036 inch (0.914 mm) 20 gage thick material with a rectangular opening of 0.315" x 0.472 " (8.0 mm x 12.0 mm).

Minor differences exist in the package between the **OPB850A** and **OPB850-1Z** (see drawings below). The cable exits the package in different locations.

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

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Pin # / Color

1-Black

2-Red

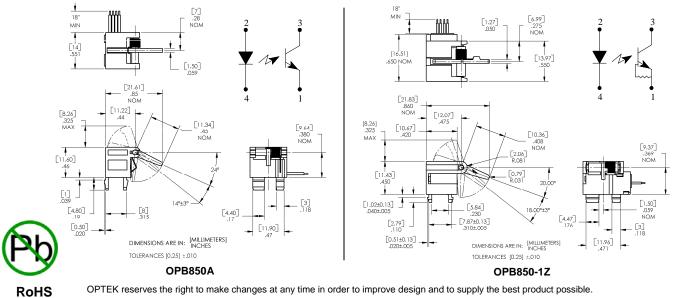
3-Brown

4-Orange

#### **Applications:**

- Non-contact interruptive object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety

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PB850-1Z			Ordering Information			
Description		Part				
Emitter		Number	Wavelength	Description		
Anode		OPB850A	940 nm	Slotted Optical Flag Switch		
Collector				18" (457 mm) wires		
Cathode		OPB850-1Z	880 nm	Slotted Optical Flag Switch 18" (457 mm) wires		
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# Slotted Optical Flag Switch OPB850A, OPB850-1Z



Absolute Maximum Ratings ( $T_A = 25^{\circ}$ C unless otherwise noted)		
Operating Temperature Range	-20° C to +75° C	
Storage Temperature Range	-40° C to +85° C	
Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 sec. with soldering iron]	260° C	
Input Diode		
Reverse Voltage	5 V	
Continuous Forward Current	50 mA	
Peak Forward Current (10 µs pulse width, 300 pps)	1 A	
Power Dissipation	75 mW	
Output Phototransistor		
Collector-Emitter Voltage	24 V	
Emitter-Collector Voltage	5 V	
Collector DC Current	20 mA	
Power Dissipation	100 mW	

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

### **Slotted Optical Flag Switch** OPB850A, OPB850-1Z



SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
nput Diod	e				1	
V <sub>F</sub>	Forward Voltage		1.2	1.6	V	I <sub>F</sub> = 20 mA
I <sub>R</sub>	I <sub>R</sub> Reverse Current		-	-	μΑ	V <sub>R</sub> = 2 V
Output Pho	ototransistor (OPB850A)					
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage		-	-	V	$I_{C} = 100 \ \mu A, E_{E} = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage		-	-	V	I <sub>E</sub> = 100 μA, E <sub>E</sub> = 0
I <sub>CEO</sub>	Collector-Emitter Dark Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, \text{ E}_{E} = 0$
Coupled (	OPB850A)					
V <sub>CE(SAT)</sub>	Collector-Emitter Saturation Voltage (1)		-	0.4	V	$I_{C} = 250 \ \mu A, I_{F} = 20 \ mA$
I <sub>C(ON)</sub>	On-State Collector Current (1)		2	-	mA	$V_{CE} = 5 \text{ V}, I_F = 20 \text{ mA}$
$I_{C(OFF)}$	FF) Off-State Collector Current <sup>(2)</sup>		-	10	μA	$V_{CE} = 5 \text{ V}, \text{ I}_{F} = 20 \text{ mA}$
Dutput Pho	ototransistor (OPB850-1Z)					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage		-	-	V	$I_{C} = 100 \ \mu A, E_{E} = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage		-	-	V	I <sub>E</sub> = 100 μA, E <sub>E</sub> = 0
I <sub>CEO</sub>	Collector-Emitter Dark Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, \text{ E}_{E} = 0$
Coupled (	OPB850-1Z)					
$V_{\text{CE}(\text{SAT})}$	Collector-Emitter Saturation Voltage (1)		-	0.40	V	$I_{C} = 500 \ \mu A, I_{F} = 20 \ mA$
I <sub>C(ON)</sub>	) On-State Collector Current (1)		2	-	mA	$V_{CE} = 10 \text{ V}, \text{ I}_{F} = 20 \text{ mA}$
I <sub>C(OFF)</sub>	Off-State Collector Current (2)	-	-	10	μA	$V_{CE} = 10 \text{ V}, I_{E} = 20 \text{ mA}$

Notes:

(1) ON (I<sub>C(ON)</sub>) electrical condition corresponds to the switch point at about 41° angular displacement of the arm.

(2) OFF (I<sub>C(OFF)</sub>) electrical condition corresponds to the mechanical arm position at rest.
(3) From the rest position to the switch point, lever torque measured at the end of the arm is 1.5 grams maximum.

(4) Wires are 26 AWG, UL rated.

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